EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	53465	refresh	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2007/11/10 11:15
L2	4631	bank adj address	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2007/11/10 11:15
L3	2034	1 and 2	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2007/11/10 11:15
L4	3596	365/222.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2007/11/10 11:16
L5	268	3 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2007/11/10 11:16
L6	20	you-min-young.in.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2007/11/10 11:16

11/10/07 11:16:21 AM C:\Documents and Settings\tphan2\My Documents\EAST\Workspaces\- trong.wsp Page 1



Day: Saturday Date: 11/10/2007

Time: 11:15:09

Inventor Name Search Result

Your Search was:

Last Name = YOU

First Name = MIN-YOUNG

	frank a				
Application#	Patent#				Inventor Name
09198521	5986956	150	11/24/1998	REPAIR CONTROL CIRCUIT	YOU, MIN-YOUNG
09304643	6111779	150	05/04/1999	CELL STRUCTURE FOR LOW ELECTRIC POWER STATIC RAM	YOU, MIN-YOUNG
09377163	6128218	150	08/19/1999	HYBRID MEMORY DEVICE	YOU, MIN-YOUNG
09461413	6359473	150	12/16/1999	AMPLIFIER FOR USE IN SEMICONDUCTOR INTEGRATED CIRCUITS	YOU, MIN-YOUNG
09562943	6208581	150	05/02/2000	Hybrid memory device and method for controlling same	YOU, MIN-YOUNG
10061372	6703871	150	02/04/2002	AMPLIFIER FOR USE IN SEMICONDUCTOR INTEGRATED CIRCUITS	YOU, MIN-YOUNG
10749350	Not Issued	80	12/31/2003	Semiconductor memory device for reducing peak current during refresh operation	YOU, MIN-YOUNG
11647176	Not Issued	30	12/29/2006	Semiconductor memory device with on die termination circuit	YOU, MIN-YOUNG
<u>11647645</u>	Not Issued	30	12/29/2006	Semiconductor memory device capable of easily performing delay locking operation under high frequency system clock	YOU, MIN-YOUNG
11819811	Not Issued	20	06/29/2007	Delay locked loop	YOU, MIN-YOUNG

Inventor Search Completed: No Records to Display.

First Name **Last Name** Search Another: Inventor you Search min-young

To go back use Back button on your browser toolbar.